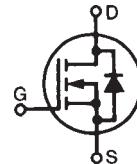


# PolarHV™ HiPerFET IXFN 102N30P Power MOSFET

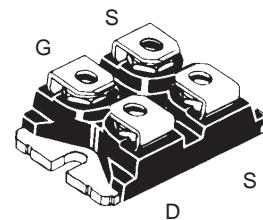
N-Channel Enhancement Mode  
Avalanche Rated  
Fast Intrinsic Diode

$V_{DSS}$  = 300 V  
 $I_{D25}$  = 86 A  
 $R_{DS(on)}$  ≤ 33 mΩ  
 $t_{rr}$  ≤ 200 ns



Symbol	Test Conditions	Maximum Ratings		
$V_{DSS}$	$T_J$ = 25°C to 150°C	300	V	
$V_{DGR}$	$T_J$ = 25°C to 150°C; $R_{GS} = 1 \text{ M}\Omega$	300	V	
$V_{GS}$	Continuous	± 20	V	
$V_{GSM}$	Transient	± 30	V	
$I_{D25}$	$T_c = 25^\circ\text{C}$	86	A	
$I_L$	Lead Current Limit, RMS	100	A	
$I_{DM}$	$T_c = 25^\circ\text{C}$ , pulse width limited by $T_{JM}$	250	A	
$I_{AR}$	$T_c = 25^\circ\text{C}$	88	A	
$E_{AR}$	$T_c = 25^\circ\text{C}$	60	mJ	
$E_{AS}$	$T_c = 25^\circ\text{C}$	5	J	
$dv/dt$	$I_S \leq I_{DM}$ , $di/dt \leq 100 \text{ A}/\mu\text{s}$ , $V_{DD} \leq V_{DSS}$ , $T_J \leq 150^\circ\text{C}$ , $R_G = 4 \Omega$	10	V/ns	
$P_D$	$T_c = 25^\circ\text{C}$	570	W	
$T_J$		-55 ... +150	°C	
$T_{JM}$		150	°C	
$T_{stg}$		-55 ... +150	°C	
$T_L$	1.6 mm (0.062 in.) from case for 10 s	300	°C	
$V_{ISOL}$	50/60 Hz, RMS	t = 1 min	2500	V~
	$I_{ISOL} \leq 1 \text{ mA}$	t = 1 s	3000	V~
$M_d$	Mounting torque	1.5 / 13	Nm/lb.in.	
	Terminal connection torque	1.5 / 13	Nm/lb.in.	
<b>Weight</b>		30	g	

miniBLOC, SOT-227 B (IXFN)  
E153432



G = Gate      D = Drain  
S = Source

Either Source terminal S can be used as the Source terminal or the Kelvin Source (gate return) terminal.

## Features

- International standard package
- Encapsulating epoxy meets UL 94 V-0, flammability classification
- miniBLOC with Aluminium nitride isolation
- Fast recovery diode
- Unclamped Inductive Switching (UIS) rated
- Low package inductance
  - easy to drive and to protect

## Advantages

- Easy to mount
- Space savings
- High power density

Symbol	Test Conditions ( $T_J = 25^\circ\text{C}$ unless otherwise specified)	Characteristic Values		
		Min.	Typ.	Max.
$BV_{DSS}$	$V_{GS} = 0 \text{ V}$ , $I_D = 250 \mu\text{A}$	300		V
$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 4 \text{ mA}$	2.5		V
$I_{GSS}$	$V_{GS} = \pm 20 \text{ V}_{DC}$ , $V_{DS} = 0$		± 200	nA
$I_{DSS}$	$V_{DS} = V_{DSS}$ , $V_{GS} = 0 \text{ V}$		25 250	μA
$R_{DS(on)}$	$V_{GS} = 10 \text{ V}$ , $I_D = 0.5 I_{D25}$ , Note 1		33	mΩ

Symbol	Test Conditions	Characteristic Values		
		Min.	Typ.	Max.
$g_{fs}$	$V_{DS} = 20 \text{ V}; I_D = 0.5 I_{D25}$ , Note 1	45	57	S
$C_{iss}$ $C_{oss}$ $C_{rss}$	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$	7500	pF	
		1150	pF	
		230	pF	
$t_{d(on)}$ $t_r$ $t_{d(off)}$ $t_f$	$V_{GS} = 10 \text{ V}, V_{DS} = 0.5 V_{DSS}, I_D = 60 \text{ A}$ $R_G = 3.3 \Omega$ (External)	30	ns	
		28	ns	
		130	ns	
		30	ns	
$Q_{g(on)}$ $Q_{gs}$ $Q_{gd}$	$V_{GS} = 10 \text{ V}, V_{DS} = 0.5 V_{DSS}, I_D = 0.5 I_{D25}$	224	nC	
		50	nC	
		110	nC	
$R_{thJC}$			0.22	°C/W
$R_{thCS}$			0.05	°C/W

## Source-Drain Diode

## Characteristic Values

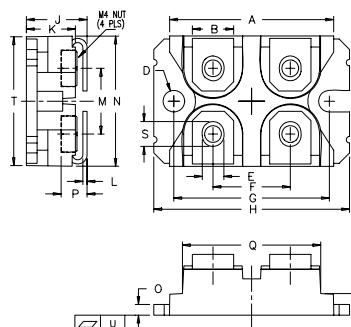
(T<sub>J</sub> = 25°C unless otherwise specified)

Symbol	Test Conditions	Min.	Typ.	Max.
$I_s$	$V_{GS} = 0 \text{ V}$		102	A
$I_{SM}$	Repetitive		250	A
$V_{SD}$	$I_F = I_s, V_{GS} = 0 \text{ V}$ , Note 1		1.5	V
$t_{rr}$ $Q_{RM}$ $I_{RM}$	$I_F = 25 \text{ A}, -di/dt = 100 \text{ A}/\mu\text{s}$ $V_R = 100 \text{ V}, V_{GS} = 0 \text{ V}$		200	ns
			0.8	μC
			6	A

## Notes:

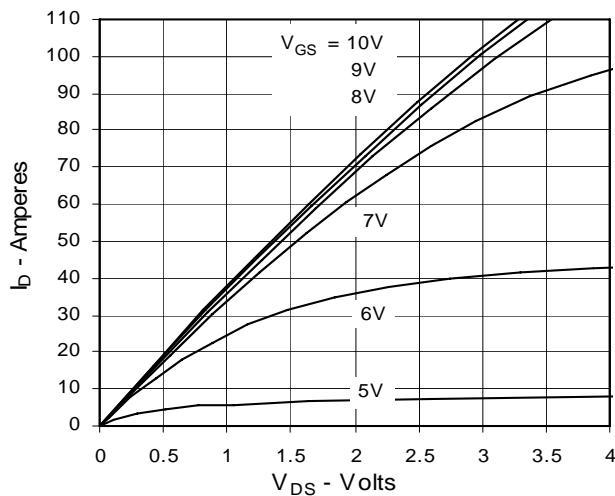
1. Pulse test, t ≤ 300 μs, duty cycle d ≤ 2 %

## SOT-227B Outline

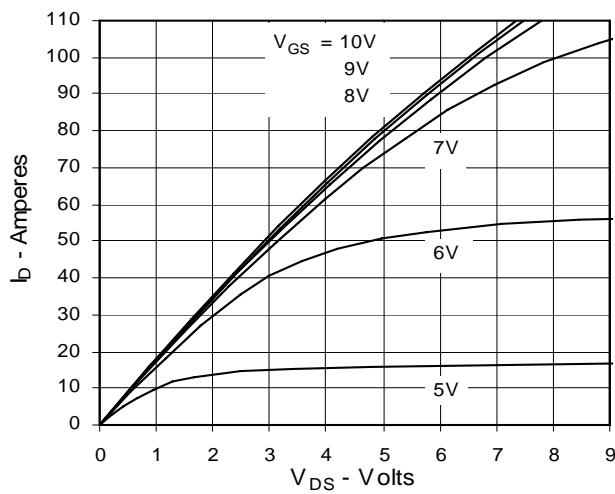


SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.240	1.255	31.50	31.88
B	.307	.323	7.80	8.20
C	.161	.169	4.09	4.29
D	.161	.169	4.09	4.29
E	.161	.169	4.09	4.29
F	.587	.595	14.91	15.11
G	1.186	1.193	30.12	30.30
H	1.496	1.505	38.00	38.23
J	.460	.481	11.68	12.22
K	.351	.378	8.92	9.60
L	.030	.033	0.76	0.84
M	.496	.506	12.60	12.85
N	.990	1.001	25.15	25.42
O	.078	.084	1.98	2.13
P	.195	.235	4.95	5.97
Q	1.045	1.059	26.54	26.90
R	.155	.174	3.94	4.42
S	.186	.191	4.72	4.85
T	.968	.987	24.59	25.07
U	-.002	.004	-0.05	0.1

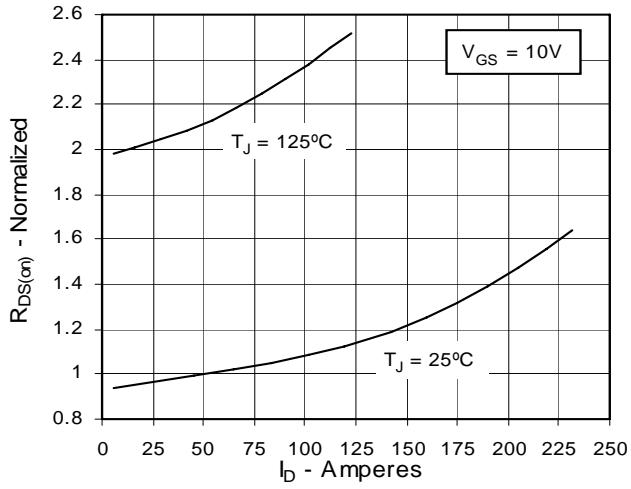
**Fig. 1. Output Characteristics  
@ 25°C**



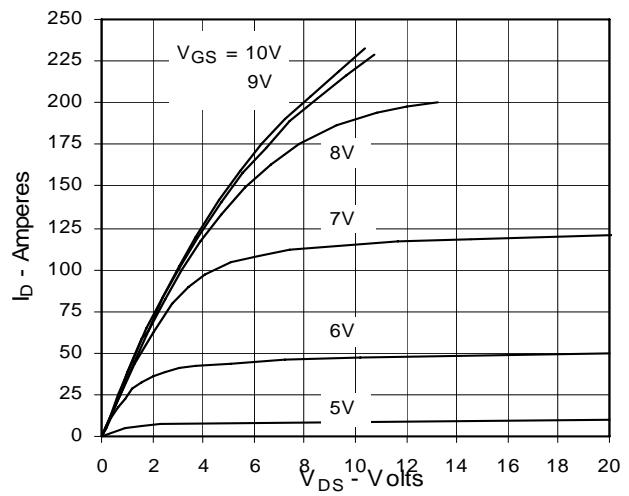
**Fig. 3. Output Characteristics  
@ 125°C**



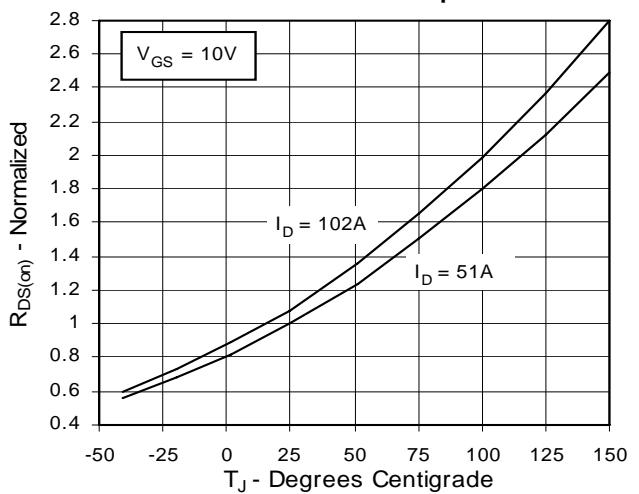
**Fig. 5.  $R_{DS(on)}$  Normalized to  
 $I_D = 51A$  Value vs. Drain Current**



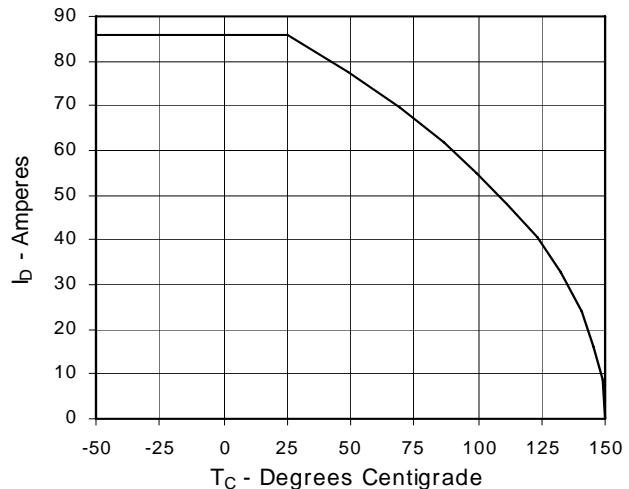
**Fig. 2. Extended Output Characteristics  
@ 25°C**

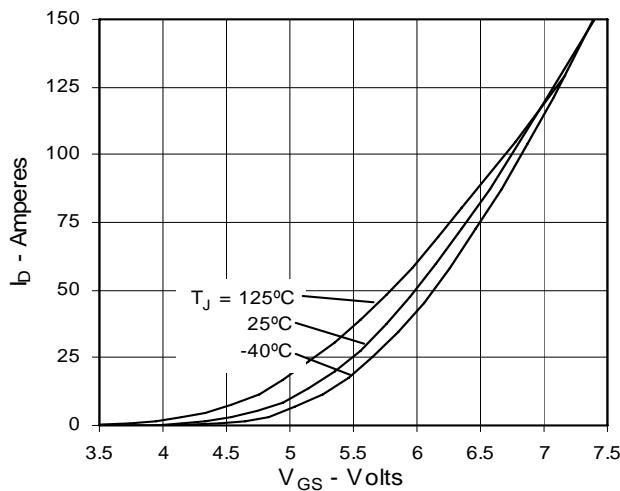
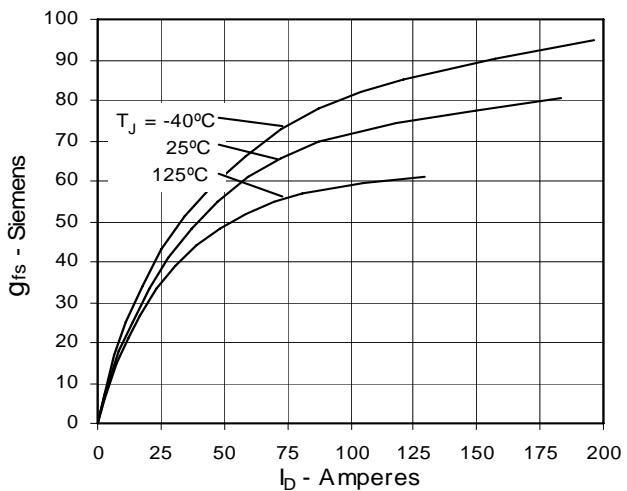
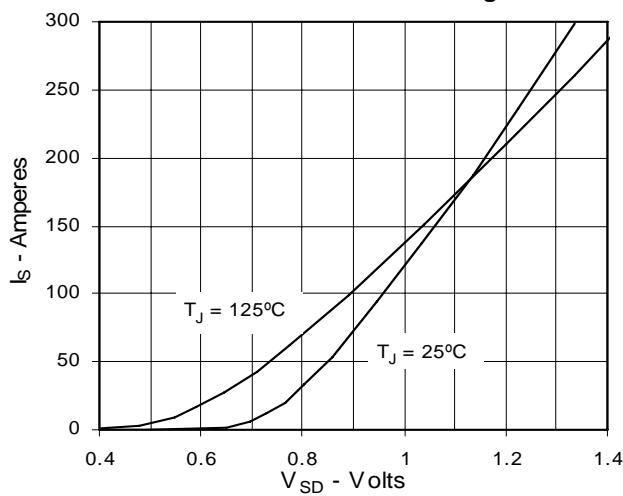
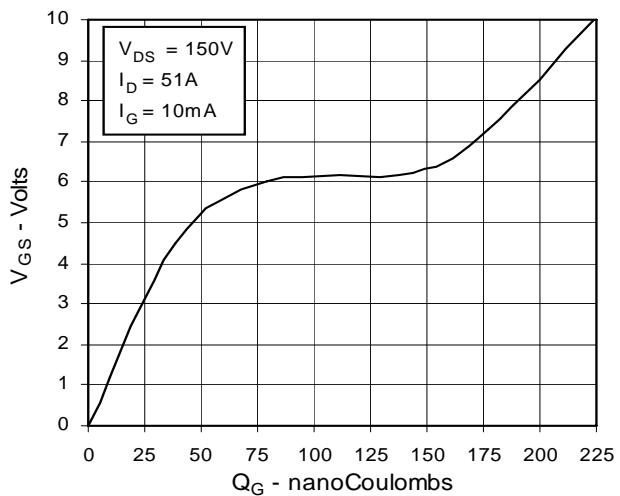
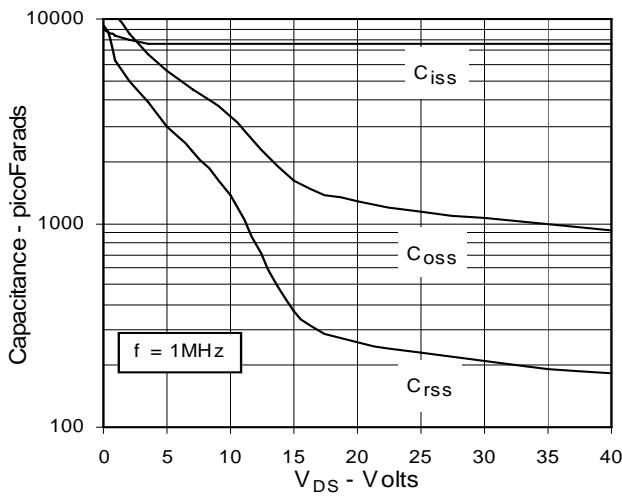
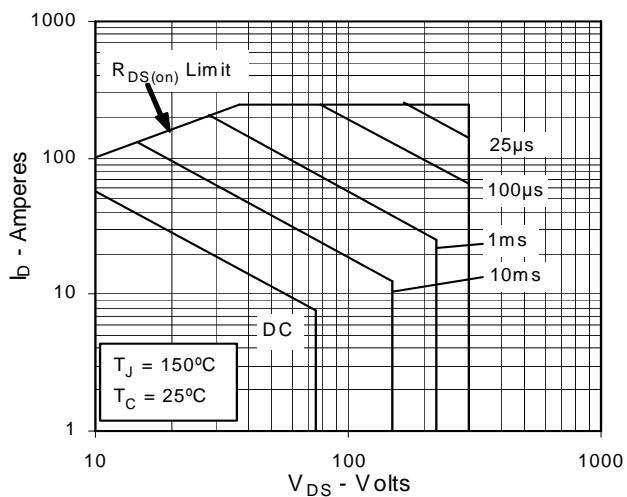


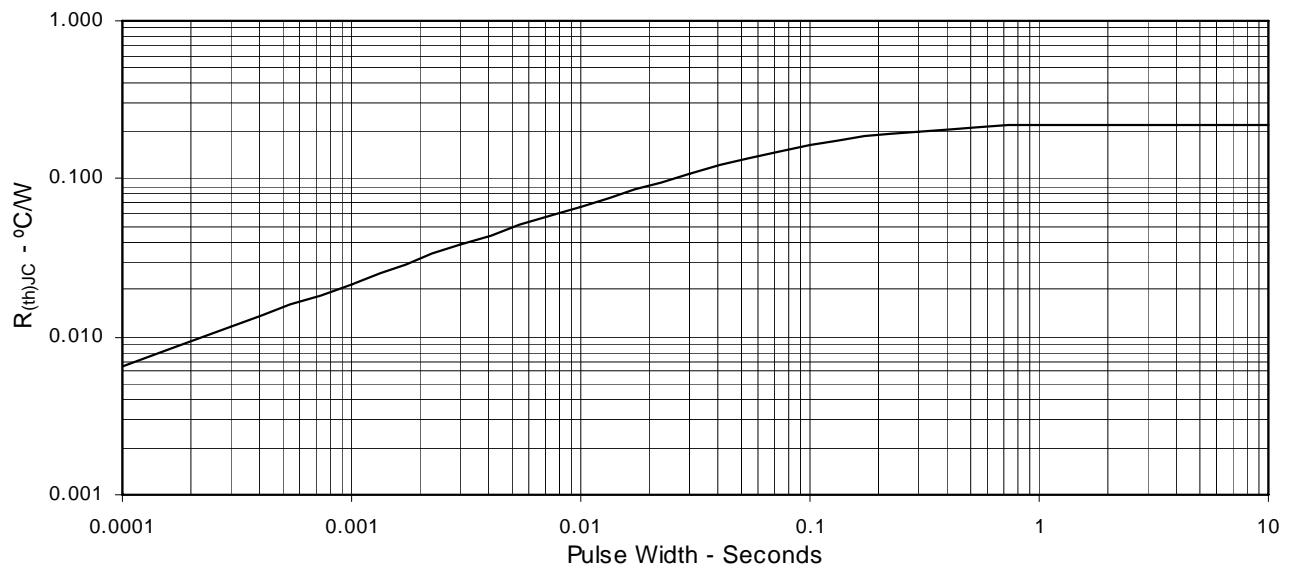
**Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D = 51A$   
Value vs. Junction Temperature**



**Fig. 6. Drain Current vs. Case  
Temperature**



**Fig. 7. Input Admittance****Fig. 8. Transconductance****Fig. 9. Source Current vs. Source-To-Drain Voltage****Fig. 10. Gate Charge****Fig. 11. Capacitance****Fig. 12. Forward-Bias Safe Operating Area**

**Fig. 13. Maximum Transient Thermal Resistance**



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